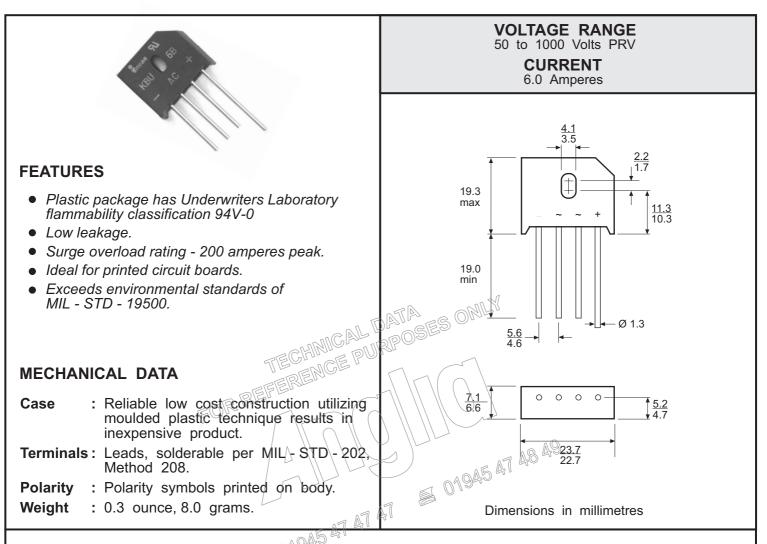


6.0 AMPERE SINGLE-PHASE SILICON BRIDGE RECTIFIER

KBU6 SER



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

			KBU6A	KBU6B	KBU6D	KBU6G	KBU6J	KBU6K	KBU6M	
Maximum Recurrent Peak Reverse Voltage		Vrrm	50	100	200	400	600	800	1000	V
Maximum Bridge Input Voltage RMS		VRMS	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage		VDC	50	100	200	400	600	800	1000	V
Maximum Average Forward Current at TA = 65°C* / Tc =100°C ** (se	ee Fig 2)	IF(AV)	6.0						Α	
Peak Forward Surge Current, 8.3 ms single half sine - wave superimposed on rated load (see	ee Fig 1)	IFSM	200					А		
Maximum Forward Voltage Drop per Element at 3.0A (se	ee Fig 3)	VF	1.0					V		
	= 25°C = 100°C	lr	10.0 1.0					μA mA		
Operating Temperature Range TJ		- 55 to + 125							°C	
Storage Temperature Range Ts		Tstg	- 55 to + 150							°C

Notes * Unit mounted on metal heatsink. ** Unit mounted on P.C board.

RATING AND CHARACTERISTIC CURVES KBU6 SERIES

